



MM 980nm 14Gbps VCSEL (Top Emission)

QZV14MM0980T101 QZV14MM0980T102 QZV14MM0980T103

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01 Descriptions Features Applications

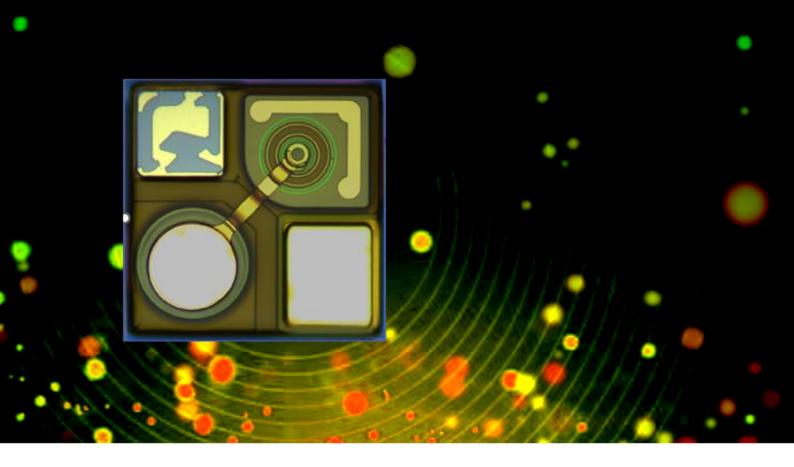
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Description

The QuantumZ - **QZV14MM0980TX0X** is multimode 14Gbps VCSEL with wavelength 980nm device has low electrical parasitics and proven high reliability. That has top side ohmic contacts with Signal-Ground (SG) configurations. The device is available in singlet (1x1) or array configurations (1x4) and are compatible with wire-bonding and flip-chip bonding.

Features

- 980nm multimode emission
- High reliability & data rates from DC to 14Gbps
- High humidity robustness compliant with GR-468
- Low threshold, operating voltage & electrical parasitic
- Available as single chip & 4 channel array
- Available application for COB & flip chip processes
- Dual top contact configuration with common cathode electrodes
- Halogen & RoHS compliant

Applications

- Smart cables & consumer applications& Automotive
- Single channel & parallel fiber optical communication links



Absolute Maximum Ratings

Parameter	Rating	Unit	
Max. operating power	6	mW	
Max. operating current	12	mA	
VCSEL reverse voltage	5	V	
Operating temperature	0 to 105	°C	
Storage temperature	-40 to 125	°C	
Mounting temperature (max. 10sec)	260	°C	

Recommended Operating Conditions

& Electro-Optic Characteristics

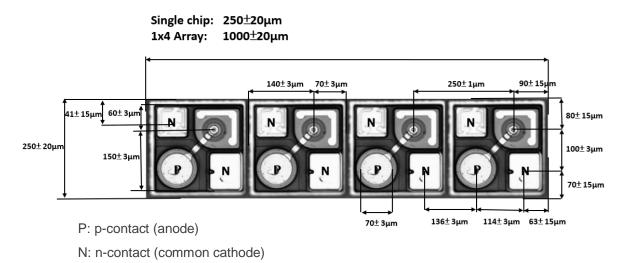
Parameter	Cumbal	Conditions	Ratings			Unit	
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit	
Threshold current	1.	T=25°C		0.6	0.8	mA	
	lth	T=105°C		0.8	1.0		
Slope efficiency	η	lop = 6.0mA, T=25°C		0.5		W/A	
Optical output power	D	lop = 6.0mA, T=25°C	2.5	3.0		~~\\/	
	Pout	lop = 6.0mA, T=105°C	2.0	2.5		mW	
Forward voltage	Vf	lop=6.0mA, T=25°C	1.9	2.1	2.3	V	
Differential resistance	R _d	lop=6mA, T=25°C~105°C		80	110	Ω	
Emission wavelength	λ	lop = 6.0mA, T=25°C~105°C	970	980	990	nm	
Spectral width, RMS	Δλ	lop=6mA, T=25°C~105°C		0.8		nm	
Wavelength Shift	dλ/dT	T = 25 °C~105 °C		0.07		nm/°C	
Modulation bandwidth	fзdВ	lop=6mA, T=25°C	15	17		GHz	
		lop=9mA, T=105°C	14	16			
Beam divergence	Θ	lop = 6.0mA, Full width 1/e2		25	30	Deg	



Chip Outer Dimensions

Parameter	Min.	Тур.	Max.
Die length	225	250	275
Die width	225	250	275
Die height	125	150	175

Chip Layout



RoHS Compliance

QuantumZ insists, via continuous improvement in technology and experiences, to utilize non-hazardous materials for manufacturing green products that are in compliance with the regulation as well as customers' GP demands. The relevant evidence of RoHS compliance is held as part of our controlled documentation for each of our compliant products.

Ordering Information

Product code	Data Rate	Description	Shipment Package
QZV14MM0980T101	14Gbps	Single VCSEL chip	Diced wafer on metal lead frame (1)
QZV14MM0980T401	14Gbps	1x4 VCSEL array	Diced wafer on metal lead frame (1)
QZV14MM0980T102	14Gbps	Single VCSEL chip	Grip ring (2)
QZV14MM0980T402	14Gbps	1x4 VCSEL array	Grip ring (2)
QZV14MM0980T103	14Gbps	Single VCSEL chip	Gel-Pak (3)
QZV14MM0980T403	14Gbps	1x4 VCSEL array	Gel-Pak (3)

(1) Full diced 4" wafer on UV tape on metal lead frame Ø 230mm, electronic wafer map provided (standard high volume)

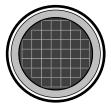
(2) Known Good Dies on UV tape on grip ring Ø 150mm (medium volume)

(3) Known Good Dies in 2" Gel-Pak (low volume)

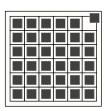


Diced wafer on UV tape on metal lead

Quantum



Grip ring



Gel-Pak

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